CY7C171A
CY7C172A

4K x 4 Static RAM with Separate I/O

Features

- **Automatic power-down when deselected**
- **CMOS for optimum speed/power**
- **High speed**
  — t_{AA} = 15 ns
- **Transparent write (7C171A)**
- **Low active power**
  — 375 mW
- **Low standby power**
  — 93 mW
- **TTL-compatible inputs and outputs**
- **Capable of withstanding greater than 2001V electrostatic discharge**

Functional Description

The CY7C171A and CY7C172A are high-performance CMOS static RAMs organized as 4096 by 4 bits with separate I/O. Easy memory expansion is provided by an active LOW chip enable ($\overline{CE}$) and three-state drivers. They have an automatic power-down feature, reducing the power consumption by 77% when deselected.

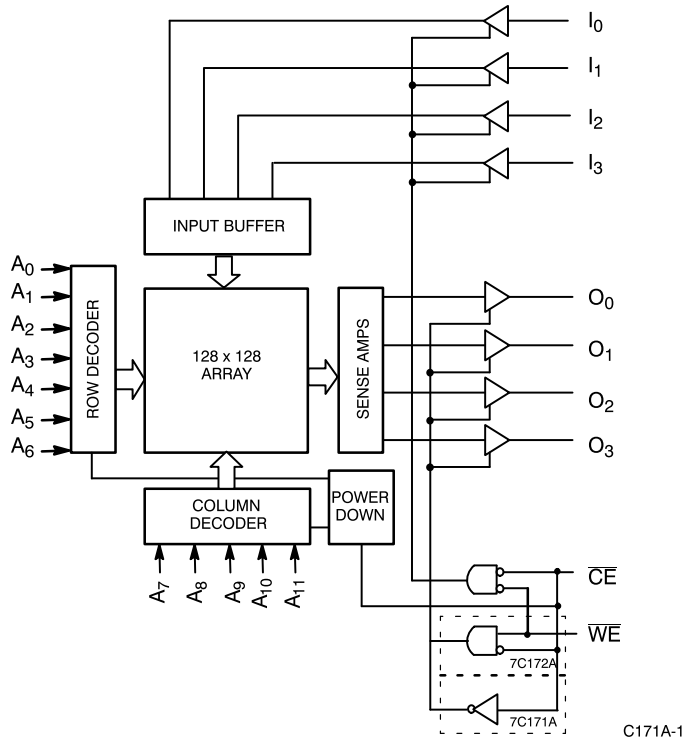
Writing to the device is accomplished when the chip enable ($\overline{CE}$) and write enable ($\overline{WE}$) inputs are both LOW. Data on the four input/output pins (I_0 through I_3) is written into the memory location specified on the address pins (A_0 through A_{11}).

Reading the device is accomplished by taking chip enable ($\overline{CE}$) LOW, while write enable ($\overline{WE}$) remains HIGH. Under these conditions the contents of the memory location specified on the address pins will appear on the four data output pins.

The output pins remain in a high-impedance state when write enable ($\overline{WE}$) is LOW (7C172A only), or chip enable is HIGH.

A die coat is used to insure alpha immunity.

Logic Block Diagram



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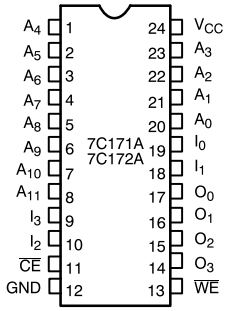
Pin Configurations

DIP/SOJ
Top View



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Selection Guide

		7C171A–15 7C172A–15	7C171A–20 7C172A–20	7C171A–25 7C172A–25	7C171A–35 7C172A–35	7C171A–45 7C172A–45
Maximum Access Time (ns)		15	20	25	35	45
Maximum Operating Current (mA)	Commercial	115	80	70	70	
	Military		90	80	70	70

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... −65°C to +150°C

Ambient Temperature with Power Applied ..... −55°C to +125°C

Supply Voltage to Ground Potential ..... −0.5V to +7.0V

DC Voltage Applied to Outputs in High Z State ..... −0.5V to +7.0V

DC Input Voltage ..... −3.0V to +7.0V

Output Current into Outputs (LOW) ..... 20 mA

Static Discharge Voltage ..... >2001V (per MIL-STD-883, Method 3015)

Latch-Up Current ..... >200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0°C to +70°C	5V ± 10%
Military[1]	−55°C to +125°C	5V ± 10%

Note:

1. T_A is the "instant on" case temperature.

Electrical Characteristics Over the Operating Range[2]

Parameter	Description	Test Conditions		7C171A−15 7C172A−15 Min.	7C171A−15 7C172A−15 Max.	7C171A−20 7C172A−20 Min.	7C171A−20 7C172A−20 Max.	7C171A−25 7C172A−25 Min.	7C171A−25 7C172A−25 Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −4.0 mA		2.4		2.4		2.4		V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 8.0 mA			0.4		0.4		0.4	V
V_{IH}	Input HIGH Voltage			2.2	V_{CC}	2.2	V_{CC}	2.2	V_{CC}	V
V_{IL}	Input LOW Voltage			−3.0	0.8	−3.0	0.8	−3.0	0.8	V
I_{IX}	Input Load Current	GND ≤ V_I ≤ V_{CC}		−10	+10	−10	+10	−10	+10	µA
I_{OZ}	Output Leakage Current	GND ≤ V_O ≤ V_{CC}, Output Disabled		−10	+10	−10	+10	−10	+10	µA
I_{OS}	Output Short Circuit Current[3]	V_{CC} = Max., V_{OUT} = GND			−350		−350		−350	mA
I_{CC}	V_{CC} Operating Supply Current	V_{CC} = Max. I_{OUT} = 0 mA	Com'l		115		80		70	mA
			Mil				90		80	mA
I_{SB1}	Automatic $\overline{CE}$ Power-Down Current	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH} Min. Duty Cycle = 100%	Com'l		40		40		20	mA
			Mil				40		20	
I_{SB2}	Automatic $\overline{CE}$ Power-Down Current	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH} − 0.3V, V_{IN} ≥ V_{CC} − 0.3V or V_{IN} ≤ 0.3V	Com'l		20		20		20	mA
			Mil				20		20	

Electrical Characteristics Over the Operating Range[2] (continued)

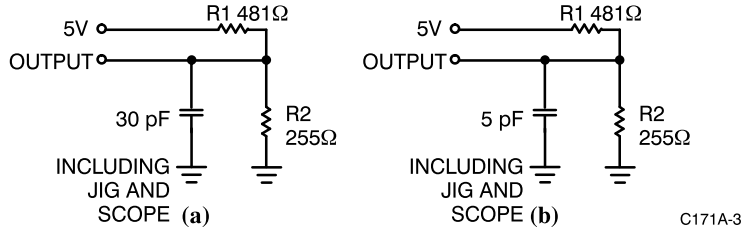
Parameter	Description	Test Conditions		7C171A−35 7C172A−35 Min.	7C171A−35 7C172A−35 Max.	7C171A−45 7C172A−45 Min.	7C171A−45 7C172A−45 Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −4.0 mA		2.4		2.4		V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 8.0 mA			0.4		0.4	V
V_{IH}	Input HIGH Voltage			2.2	V_{CC}	2.2	V_{CC}	V
V_{IL}	Input LOW Voltage			−3.0	0.8	−3.0	0.8	V
I_{IX}	Input Load Current	GND ≤ V_I ≤ V_{CC}		−10	+10	−10	+10	μA
I_{OZ}	Output Leakage Current	GND ≤ V_O ≤ V_{CC}, Output Disabled		−10	+10	−10	+10	μA
I_{OS}	Output Short Circuit Current[3]	V_{CC} = Max., V_{OUT} = GND			−350		−350	mA
I_{CC}	V_{CC} Operating Supply Current	V_{CC} = Max. I_{OUT} = 0 mA	Com'l		70			mA
			Mil		70		70	mA
I_{SB1}	Automatic $\overline{CE}$ Power-Down Current	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH} Min. Duty Cycle = 100%	Com'l		20			mA
			Mil		20		20	
I_{SB2}	Automatic $\overline{CE}$ Power-Down Current	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH} − 0.3V, V_{IN} ≥ V_{CC} − 0.3V or V_{IN} ≤ 0.3V	Com'l		20			mA
			Mil		20		20	

Capacitance[4]

Parameter	Description	Test Conditions	Max.	Unit
C_{IN}	Input Capacitance	T_A = 25°C, f = 1 MHz, V_{CC} = 5.0V	10	pF
C_{OUT}	Output Capacitance		10	pF

Notes:
2. See the last page of this specification for Group A subgroup testing information.
3. Not more than 1 output should be shorted at one time. Duration of the short circuit should not exceed 30 seconds.
4. Tested initially and after any design or process changes that may affect these parameters

AC Test Loads and Waveforms



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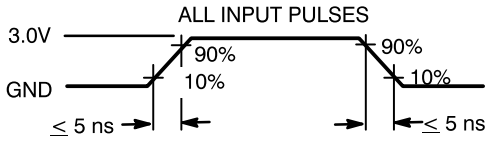

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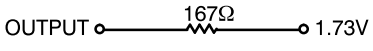
Equivalent to: THÉVENIN EQUIVALENT



Switching Characteristics Over the Operating Range[2,5]

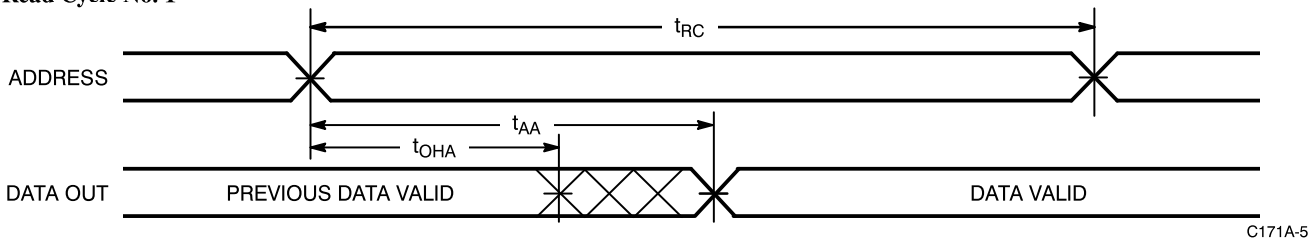
Parameter	Description	7C171A−15 7C172A−15		7C171A−20 7C172A−20		7C171A−25 7C172A−25		7C171A−35 7C172A−35		7C171A−45 7C172A−45		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE												
t_{RC}	Read Cycle Time	15		20		25		35		45		ns
t_{AA}	Address to Data Valid		15		20		25		35		45	ns
t_{OHA}	Output Hold from Address Change	5		5		5		5		5		ns
t_{ACE}	$\overline{CE}$ LOW to Data Valid		15		20		25		35		45	ns
t_{LZCE}	$\overline{CE}$ LOW to LOW Z[6]	5		5		5		5		5		ns
t_{HZCE}	$\overline{CE}$ HIGH to HIGH Z[6, 7]		8		8		10		15		15	ns
t_{PU}	$\overline{CE}$ LOW to Power Up	0		0		0		0		0		ns
t_{PD}	$\overline{CE}$ HIGH to Power Down		15		20		20		20		25	ns
t_{RCS}	Read Command Set-Up	0		0		0		0		0		ns
t_{RCH}	Read Command Hold	0		0		0		0		0		ns
WRITE CYCLE[8]												
t_{WC}	Write Cycle Time	15		20		20		25		40		ns
t_{SCE}	$\overline{CE}$ LOW to Write End	12		15		20		25		30		ns
t_{AW}	Address Set-Up to Write End	12		15		20		25		30		ns
t_{HA}	Address Hold from Write End	0		0		0		0		0		ns
t_{SA}	Address Set-Up to Write Start	0		0		0		0		0		ns
t_{PWE}	$\overline{WE}$ Pulse Width	12		15		15		20		20		ns
t_{SD}	Data Set-Up to Write End	10		10		10		15		15		ns
t_{HD}	Data Hold from Write End	0		0		0		0		0		ns
t_{LZWE}	$\overline{WE}$ HIGH to Low Z[6] (7C172A)	5		5		5		5		5		ns
t_{HZWE}	$\overline{WE}$ LOW to High Z[6, 7] (7C172A)		7		7		7		10		15	ns
t_{AWE}	$\overline{WE}$ LOW to Data Valid (7C171A)		15		20		25		30		35	ns
t_{ADV}	Data Valid to Output Valid (7C171A)		15		20		25		30		35	ns

Notes:

5. Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading of the specified I_{OI}/I_{OH} and 30-pF load capacitance.
6. At any given temperature and voltage condition, t_{HZ} is less than t_{LZ} for any given device.
7. t_{HZCE} and t_{HZWE} are tested with C_L = 5pF as in part (b) of AC Test Loads. Transition is measured ±500 mV from steady state voltage.
8. The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
9. $\overline{WE}$ is HIGH for read cycle.
10. Device is continuously selected, $\overline{CE}$ = V_{IL}.
11. Address valid prior to or coincident with $\overline{CE}$ transition LOW.
12. If $\overline{CE}$ goes HIGH simultaneously with $\overline{WE}$ HIGH, the output remains in a high-impedance state (7C172A).

Switching Waveforms

Read Cycle No. 1[9, 10]



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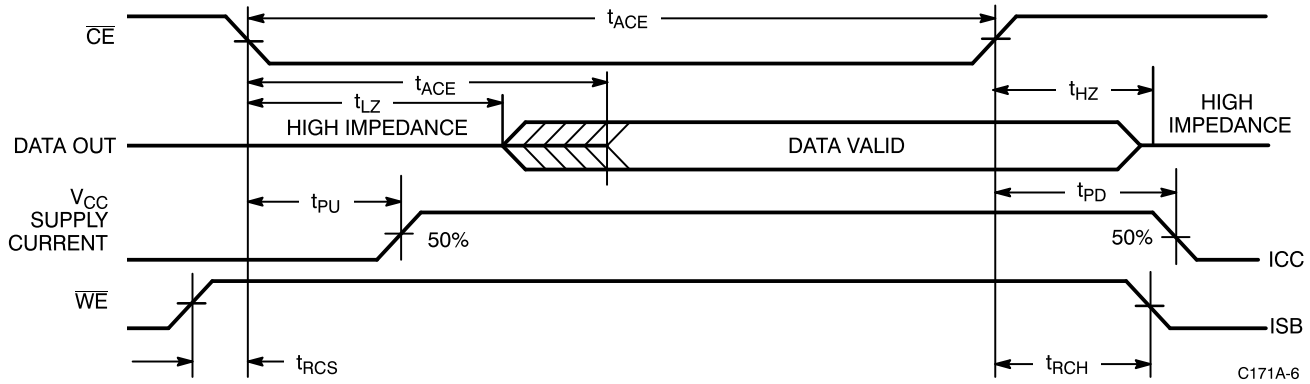
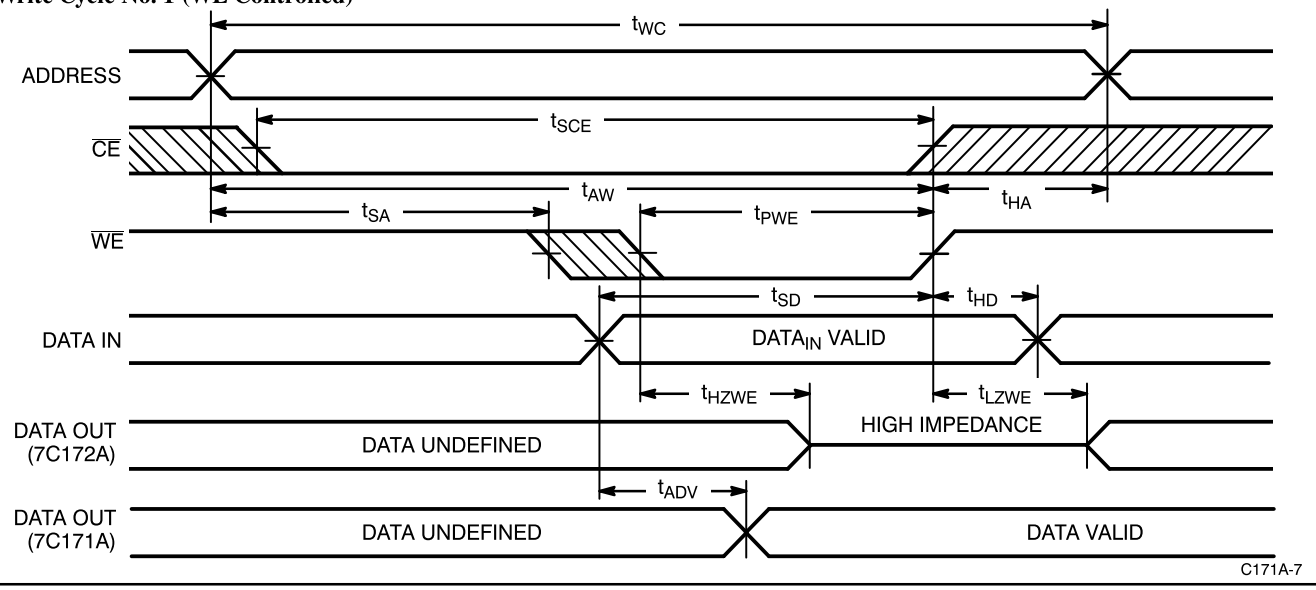
Switching Waveforms (continued)

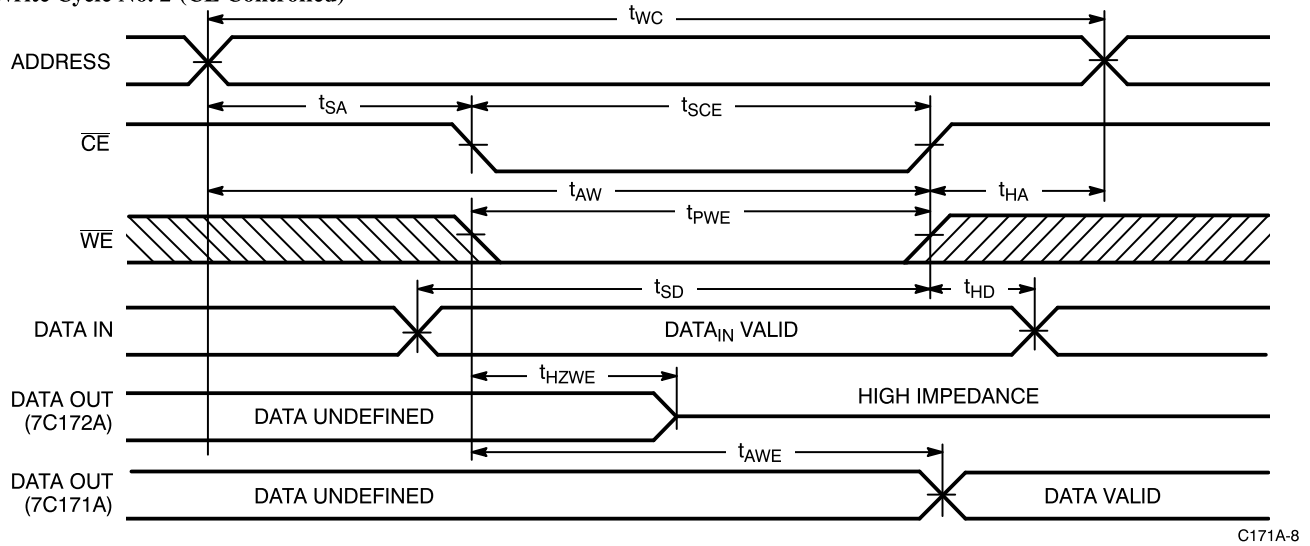
Read Cycle No. 2[9, 11]



Write Cycle No. 1 (WE Controlled)[8]

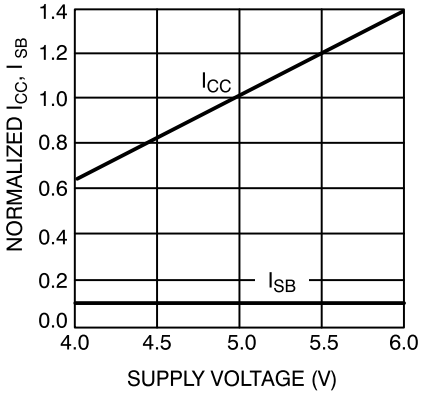


Write Cycle No. 2 (CE Controlled)[8, 12]

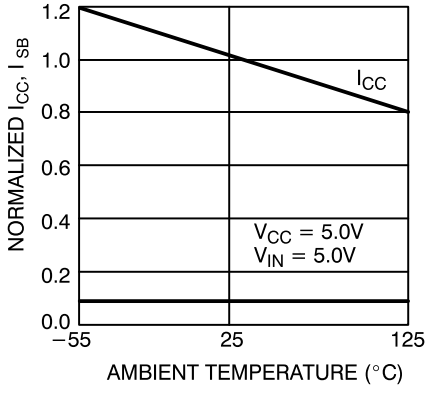


Typical DC and AC Characteristics

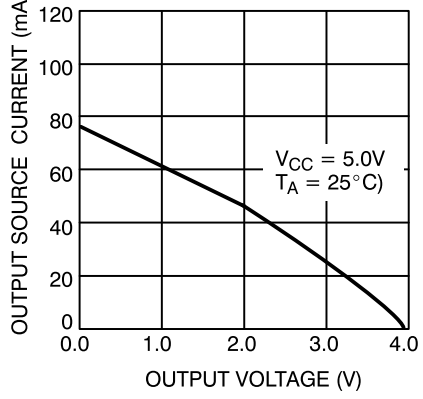
NORMALIZED SUPPLY CURRENT vs. SUPPLY VOLTAGE



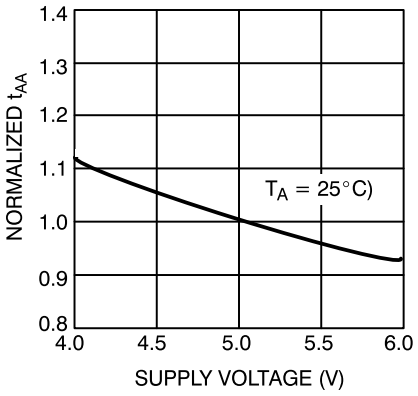
NORMALIZED SUPPLY CURRENT vs. AMBIENT TEMPERATURE



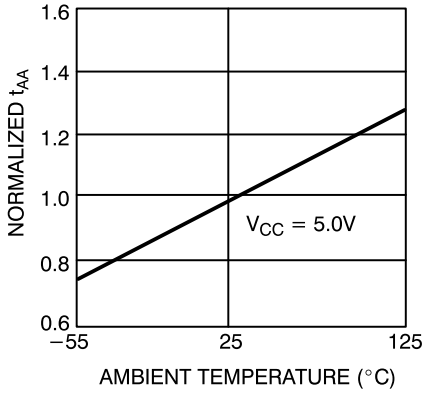
OUTPUT SOURCE CURRENT vs. OUTPUT VOLTAGE



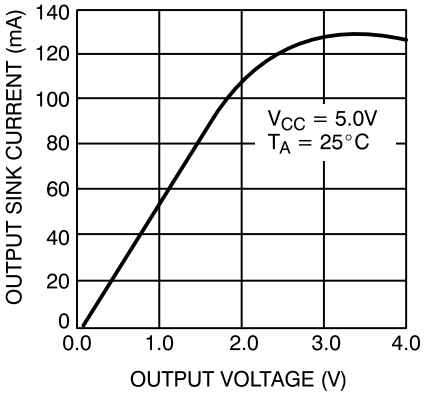
NORMALIZED ACCESS TIME vs. SUPPLY VOLTAGE



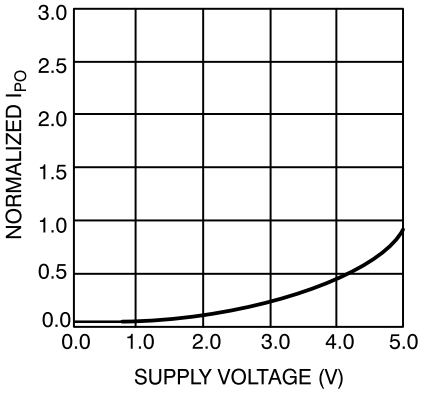
NORMALIZED ACCESS TIME vs. AMBIENT TEMPERATURE



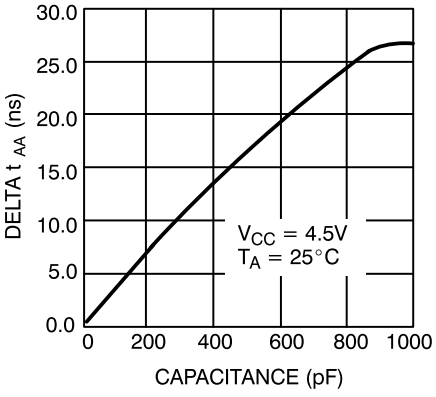
OUTPUT SINK CURRENT vs. OUTPUT VOLTAGE



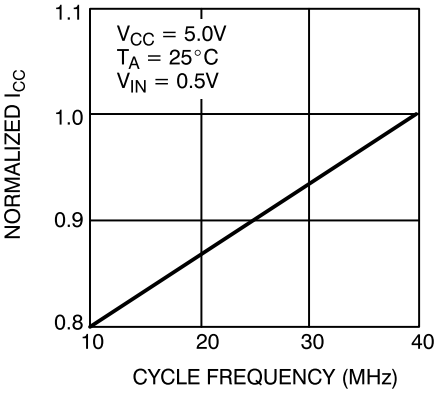
TYPICAL POWER-ON CURRENT vs. SUPPLY VOLTAGE



TYPICAL ACCESS TIME CHANGE vs. OUTPUT LOADING



NORMALIZED I_{CC} vs. CYCLE TIME



Ordering Information

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C171A−15PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
20	CY7C171A−20PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
25	CY7C171A−25PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
35	CY7C171A−35PC	P13	24-Lead (300-Mil) Molded DIP	Commerical

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C172A−15PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
	CY7C172A−15VC	V13	24-Lead Molded SOJ	
20	CY7C172A−20PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
	CY7C172A−20VC	V13	24-Lead Molded SOJ	
	CY7C172A−20DMB	D14	24-Lead (300-Mil) CerDIP	Military
25	CY7C172A−25PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
	CY7C172A−25VC	V13	24-Lead Molded SOJ	
	CY7C172A−25DMB	D14	24-Lead (300-Mil) CerDIP	Military
35	CY7C172A−35PC	P13	24-Lead (300-Mil) Molded DIP	Commercial
	CY7C172A−35DMB	D14	24-Lead (300-Mil) CerDIP	Military
45	CY7C172A−45DMB	D14	24-Lead (300-Mil) CerDIP	Military

MILITARY SPECIFICATIONS

Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V_{OH}	1, 2, 3
V_{OL}	1, 2, 3
V_{IH}	1, 2, 3
V_{IL} Max.	1, 2, 3
I_{IX}	1, 2, 3
I_{OZ}	1, 2, 3
I_{OS}	1, 2, 3
I_{CC}	1, 2, 3
I_{SB1}	1, 2, 3
I_{SB1}	1, 2, 3

Switching Characteristics

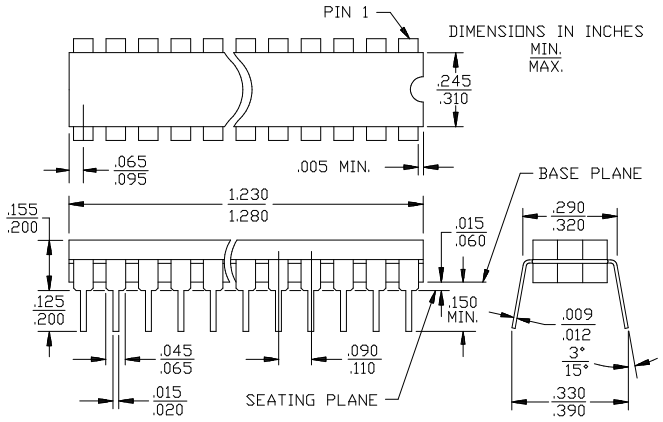
Parameter	Subgroups
READ CYCLE	
t_{RC}	7, 8, 9, 10, 11
t_{AA}	7, 8, 9, 10, 11
t_{OHA}	7, 8, 9, 10, 11
t_{ACE}	7, 8, 9, 10, 11
t_{RCS}	7, 8, 9, 10, 11
t_{RCH}	7, 8, 9, 10, 11
WRITE CYCLE	
t_{WC}	7, 8, 9, 10, 11
t_{SCE}	7, 8, 9, 10, 11
t_{AW}	7, 8, 9, 10, 11
t_{HA}	7, 8, 9, 10, 11
t_{SA}	7, 8, 9, 10, 11
t_{PWE}	7, 8, 9, 10, 11
t_{SD}	7, 8, 9, 10, 11
t_{HD}	7, 8, 9, 10, 11
t_{AWE}[13]	7, 8, 9, 10, 11
t_{ADV}[13]	7, 8, 9, 10, 11

Note:
13. 7C171A only.

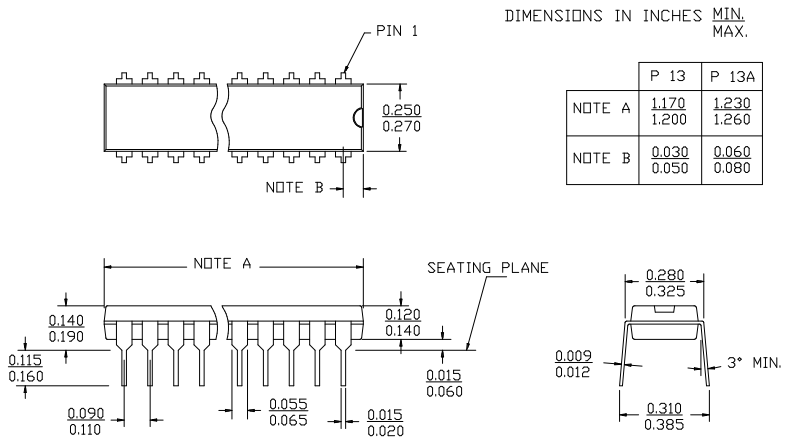
Document #: 38−00104−D

Package Diagrams

24-Lead (300-Mil) CerDIP D14
MIL−STD−1835 D−9 Config. A



24-Lead (300-Mil) Molded DIP P13/P13A



	P 13	P 13A
NOTE A	1.170 1.200	1.230 1.260
NOTE B	0.030 0.050	0.060 0.080

Package Diagrams (continued)

24-Lead Molded SOJ V13